Slew Rate Controlled Load Switch

General Description

The ET3138 advanced load management switches target applications requiring a highly integrated solution it disconnects loads powered from DC Power Rail (< 5.5V) with stringent off-state current targets. Each switch consists of slew-rate controlled low-impedance MOSFET Switch (40mΩ Typ) and other integrated analog features. The slew-rate controlled turn-on characteristic prevents inrush-current and the resulting excessive voltage droop on power rails.

These devices have exceptionally low off-state current drain (< 1μA max) which facilitate compliance in very low stand-by power applications. The input voltage range operates from 1.2V to 5.5V DC to fulfill a wide range of applications in consumer, optical, medical, storage, portable, and industrial device power management. Switch control is managed by a logic input (Active HIGH) capable of interfacing directly with low voltage control signal/GPIO with no external pull-down resistor required.

Features

- 1.2V to 5.5V Input Voltage Operating Range
- Typical $R_{DS(ON)}$:

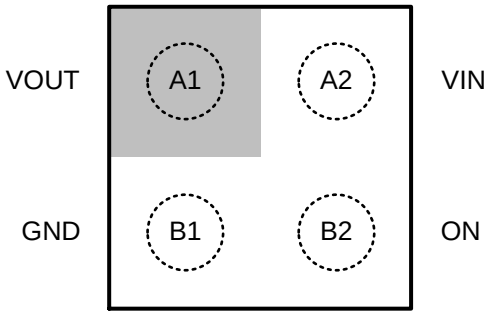
  -- 40mΩ at V_{IN}=5.5V
  -- 50mΩ at V_{IN}=3.3V
  -- 90mΩ at V_{IN}=1.8V
  -- 180mΩ at V_{IN}=1.2V
- Slew Rate/Inrush Control with t_R: 60us (Typ)
- 2.2A Maximum Continuous Current Capability
- Low < 1μA Off Switch Current
- Logic CMOS IO meets JESD76 standard
- ESD Protected: Above 8kV HBM, 2kV CDM
- Part No. and Package

Part No.	Package	MSL
ET3138	WLCSP4 (0.76mm × 0.76mm)	Level 1

Application

- Smartphones, Tablet PC
- HDD, Storage, and Solid State Memory Devices
- SLR Digital Cameras
- GPS and Navigation Equipment
- Industrial Handheld and Enterprise Equipment

Pin Configuration

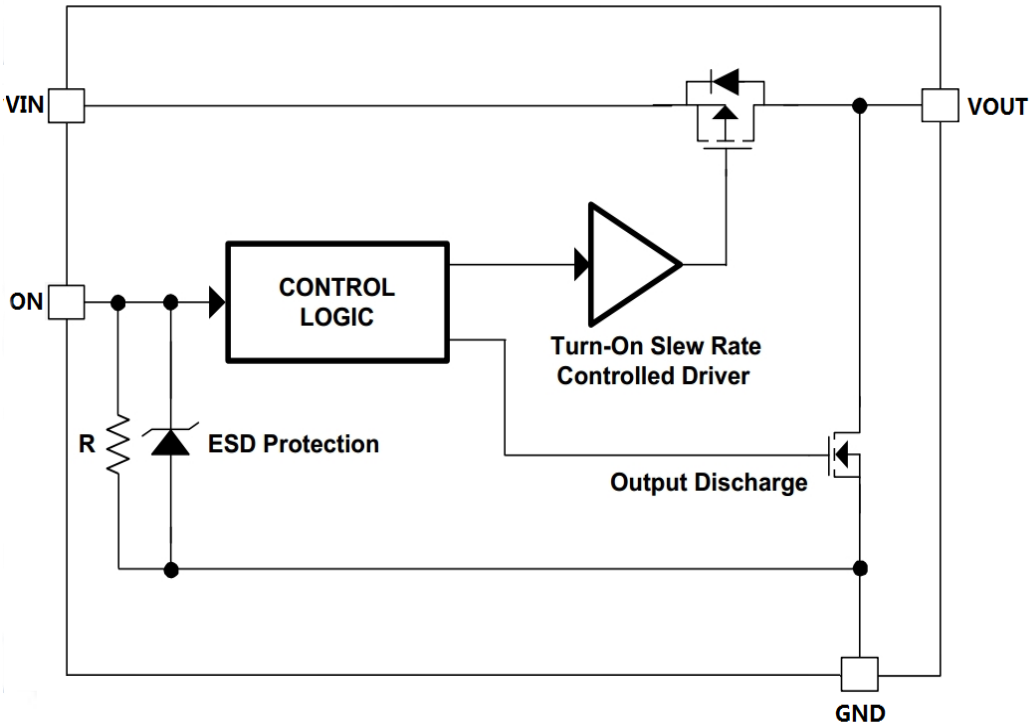


Top view (Figure 1)

Pin Function

Pin	Name	Description
A1	VOUT	Switch Output
A2	VIN	Supply Input: Input to the Power Switch
B1	GND	Ground
B2	ON	ON/OFF Control, Active HIGH Compatible

Block Diagram



Functional Block Diagram (Figure 2)

Functional Description

The ET3138 is low-R_{ON} P-channel load switches with controlled turn-on. The core of each device is a 40mΩ P-channel MOSFET and controller capable of functioning over a wide input operating range of 1.2～5.5V. The ON pin, an active High GIOP input, controls the state of the switch.

Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor or short-circuit, a capacitor must be placed between the VIN and GND pins. A 1μF ceramic capacitor, C_{IN}, placed close to the pins is usually sufficient. Higher-value C_{IN} can be used to reduce the voltage drop in higher-current applications.

Output Capacitor

A 0.1μF capacitor, C_{OUT}, should be placed between the VOUT and GND pins. This capacitor prevents parasitic board inductance from forcing V_{OUT} below GND when the switch is on. C_{IN} greater than C_{OUT} is highly recommended. C_{OUT} greater than C_{IN} can cause V_{OUT} to exceed V_{IN} when the system supply is removed. This could result in current flow through the body diode from V_{OUT} to V_{IN}.

Board Layout

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effect that parasitic trace inductance may have on normal and short-circuit operation. Using wide traces or large copper planes for all pins (V_{IN}, V_{OUT}, ON, and GND) helps minimize the parasitic electrical effects along with minimizing the case ambient thermal impedance.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameters (Items)	Value	Unit
V_{IN}	IN Voltage	-0.3 to 6.5	V
V_{ON}	ON Voltage	-0.3 to 6.5	V
V_{OUT}	Output Voltage	-0.3 to 6.5	V
I_{MAX}	Maximum Continuous Switch Current	2.2	A
P_D	Maximum Power Consumption	1.0	W
V_{ESD}	Human Body Model (JEDEC JS-001)	±8000	V
	Charged Device Model (JEDEC JS-002)	±2000	V
$R_{\theta JA}$	Junction-to-ambient Thermal Resistance	100	°C/W
T_J	Junction Temperature Range	-40 to 150	°C
T_{STG}	Storage Temperature	-65 to 150	°C

Recommended Operating Conditions

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage	1.2 to 5.5	V
T_A	Operating Ambient Temperature	-40 to 85	°C
C_{IN}	Effective Input Ceramic Capacitor Value	0.47 to 10	μF
C_{OUT}	Effective Output Ceramic Capacitor Value	0.047 to 1	μF

Electrical Characteristics

(Unless otherwise noted, V_{IN}=1.2 to 5.5V, T_A=-40 to +85°C; typical values are at V_{IN}=3.3V and T_A=25°C)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
Basic Operation						
V_{IN}	Input Voltage		1.2		5.5	V
I_{Q_OFF}	Off Supply Current	V_{ON}=GND,V_{OUT}=Open		0.1	1.0	μA
I_{SD}	Shutdown Current	V_{ON}=GND,V_{OUT}=GND		0.1	1.0	μA
I_{Q_ON}	Quiescent Current	I_{OUT} = 0mA		0.5	1.2	μA
R_{ON}	On-Resistance	V_{IN} =5.5V,I_{OUT}=200mA,T_A=25°C	30	40	50	mΩ
		V_{IN}=3.3V,I_{OUT}=200mA,T_A=25°C	35	50	65	
		V_{IN}=1.8V,I_{OUT}=200mA,T_A=25°C	70	90	110	
		V_{IN}=1.2V,I_{OUT}=200mA,T_A=25°C	140	180	220	
V_{IH}	ON Input Logic High Voltage	V_{IN}=1.2V to 5.5V	1.0			V
V_{IL}	ON Input Logic Low Voltage	V_{IN}=1.2V to 5.5V			0.55	V
R_{ON_PD}	Pull-Down Resistance at ON pin	T_A=25°C	5.5	7.0	10.5	MΩ
R_{PD}	OUT pin Discharge Resistance	V_{IN}= 3.3V, V_{ON}=GND V_{OUT}=1V, T_A=25°C	30	60	80	Ω
I_{ON}	On Input Leakage	V_{ON}=V_{IN} or GND,T_A=25°C		0.5	1.0	μA
Dynamic Characteristics: See Definitions Below						
t_{DON}	Turn-On Delay[1,2]	V_{IN}=3.3V,R_L=10Ω, C_L=0.1μF,T_A=25°C		40		μs
t_R	V_{OUT} Rise Time[1,2]			60		μs
t_{ON}	Turn-On Time[1,3]			100		μs
t_{DOFF}	Turn-Off Delay[1,2]	V_{IN}=3.3V,R_L=10Ω, C_L=0.1μF,T_A=25°C		5.5		μs
t_F	V_{OUT} Fall Time[1,2]			1.3		μs
t_{OFF}	Turn-Off Time[1,4]			6.8		μs

Notes:

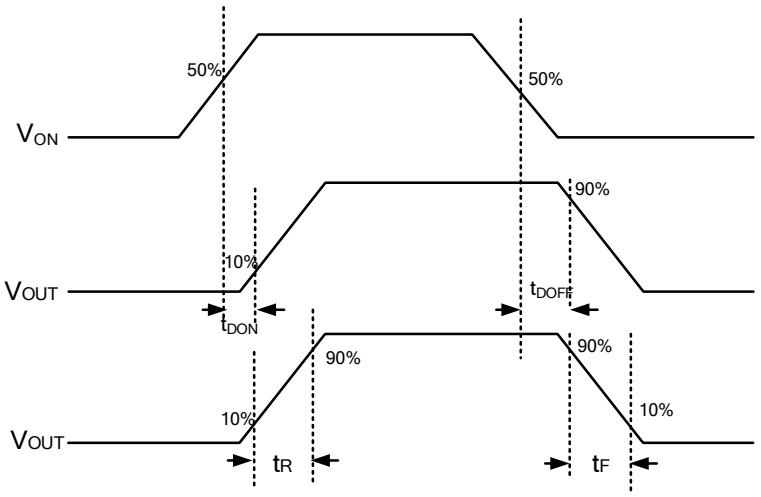
1. This parameter is guaranteed by design and characterization; not production tested.

2. t_{DON}/t_{DOFF}/t_R/t_F are defined in Figure 3.

3. t_{ON}=t_R + t_{DON}

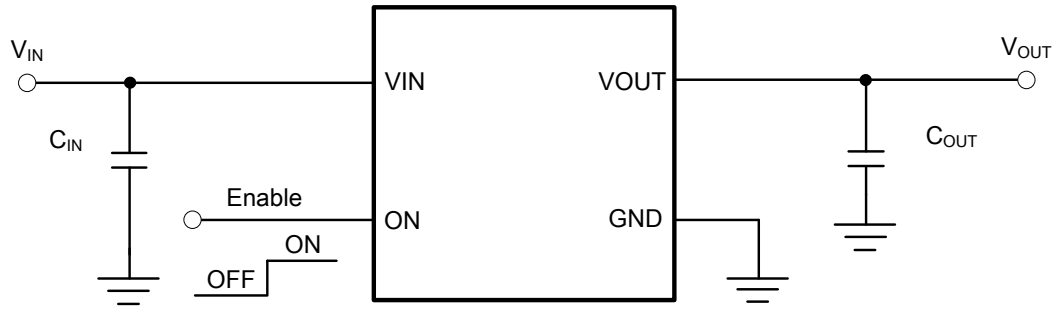
4. t_{OFF}=t_F + t_{DOFF}

Timing Diagram



Timing Diagram (Figure 3)

Application Circuits



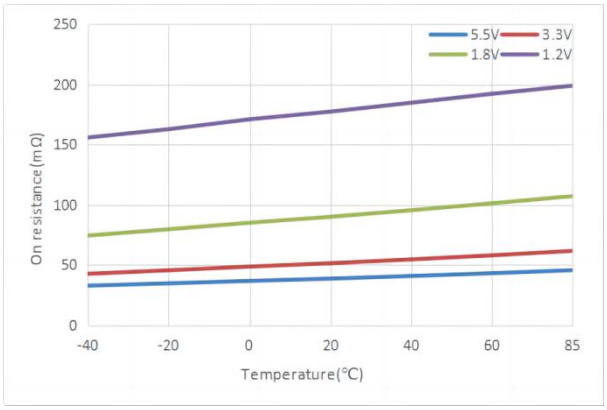
Typical Application (Figure 4)

*：This electric circuit only supplies for reference.

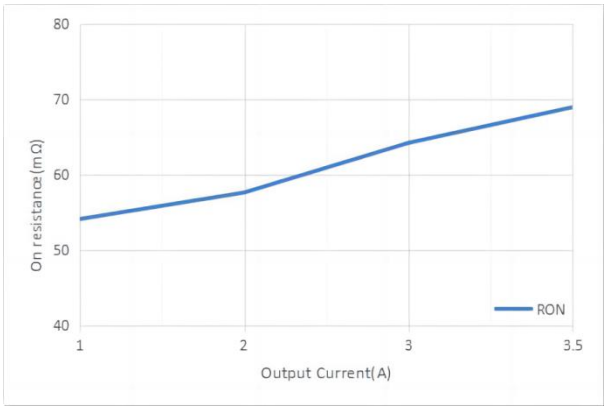
Recommend Capacitor Value: C_{IN}=1uF,C_{OUT}=0.1uF

Typical Characteristics

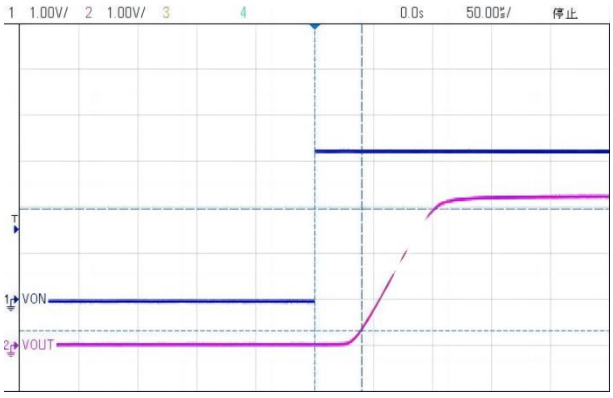
Unless otherwise noted, V_{IN}=1.2 to 5.5V, T_A= -40 to +85°C; typical values are at V_{IN}=3.3V and T_A=25°C



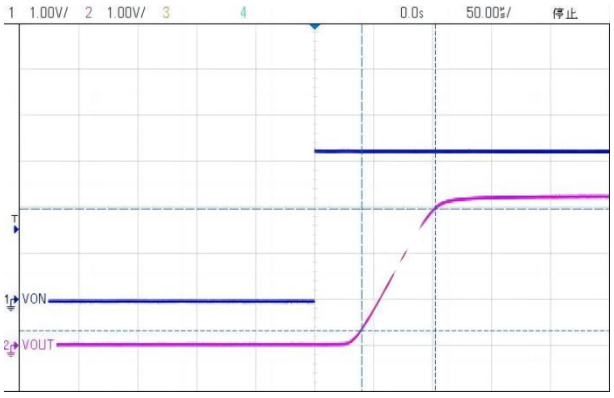
On resistance VS Temperature



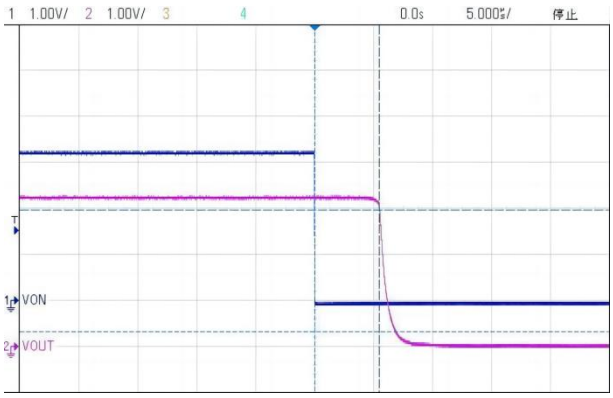
On resistance VS Output current (3.3V)



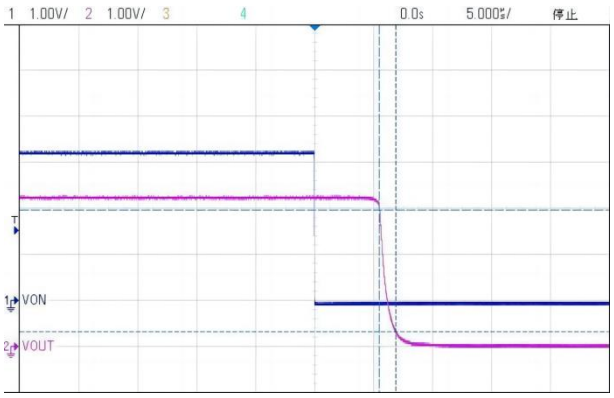
t_{DON}=40us



t_R=60us



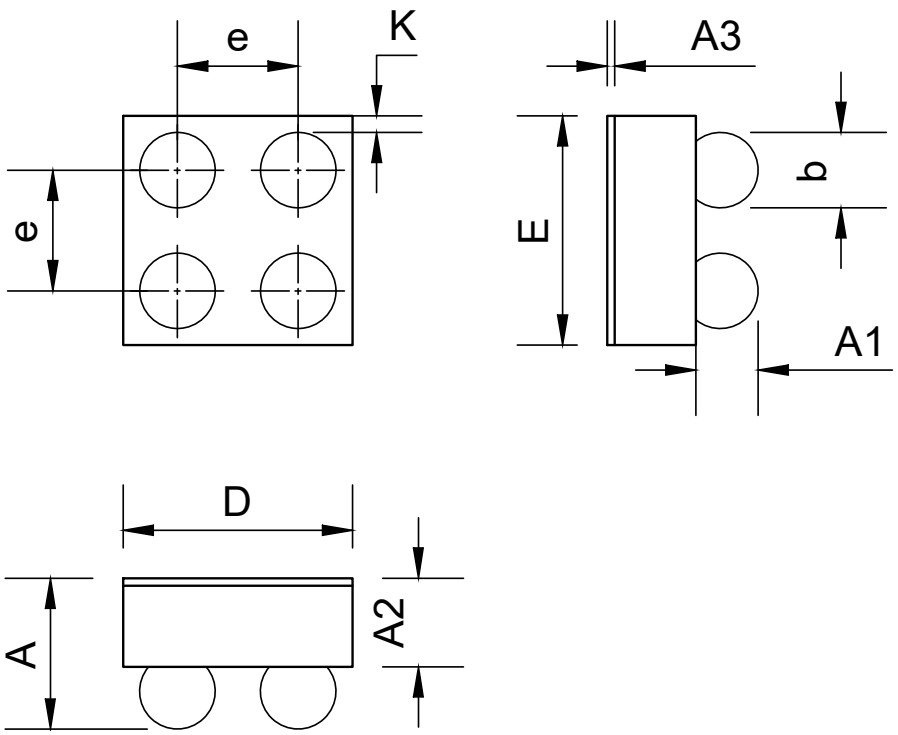
t_{DOFF}=5.5 us



t_F=1.3 us

Package Dimension

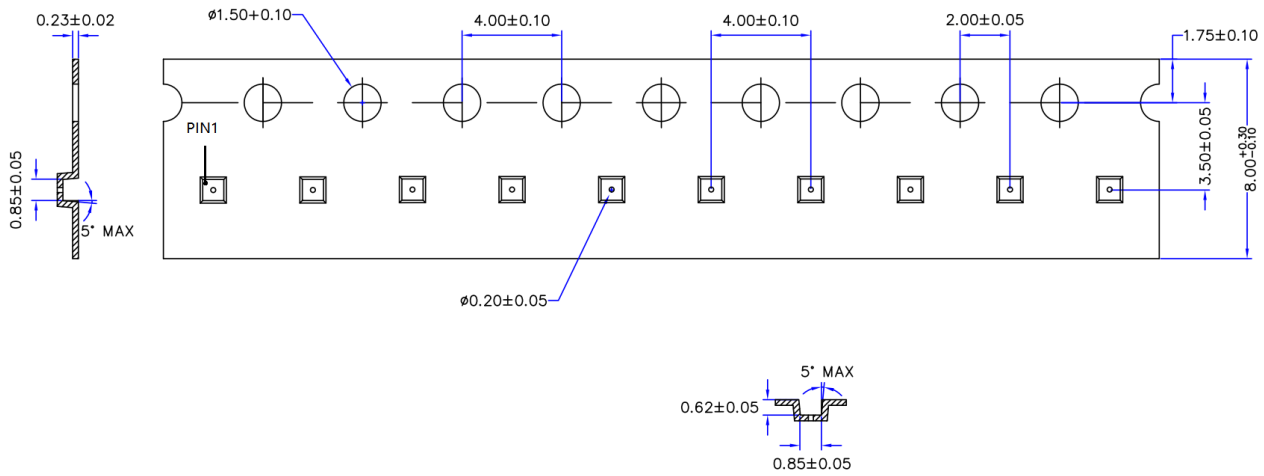
WLCSP4



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	0.46	0.50	0.54
A1	0.181	0.206	0.231
A2	0.269	0.294	0.319
A3		0.025REF	
b	0.22	0.25	0.28
D	0.73	0.76	0.79
E	0.73	0.76	0.79
e		0.40BSC	
K		0.055REF	

Tape Information



Unit: mm

Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2019-04-28	Preliminary Version	Luh	Luh	Zhujl
1.1	2019-06-28	Add 1.2V RON Add the MIN value in the RPD.	Luh	Luh	Zhujl
1.2	2020-03-13	Documents check and formalize	Shib	Shib	Liujy
1.3	2020-09-25	Update Block Diagram	Luh	Luh	Liujy
1.4	2020-10-22	Add Typical Characteristic Picture	Shib	Shib	Liujy
1.5	2021-12-23	Add Tape & Marking Information	Luh	Luh	Liujy
1.6	2023-11-25	Update Typesetting	Shib	Luh	Liujy